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Electronic and Magnetic Characterization of Epitaxial CrBr₃ Monolayers on a Superconducting Substrate

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The ability to imprint a given material property to another through a proximity effect in layered 2D materials has opened the way to the creation of designer materials. Here, molecular-beam epitaxy is used for direct synthesis of a superconductor–ferromagnet heterostructure by combining superconducting niobium diselenide (NbSe₂) with the monolayer ferromagnetic chromium tribromide (CrBr₃). Using different characterization techniques and density-functional theory calculations, it is confirmed that the CrBr₃ monolayer retains its ferromagnetic ordering with a magnetocrystalline anisotropy favoring an out-of-plane spin orientation. Low-temperature scanning tunneling microscopy measurements show a slight reduction of the superconducting gap of NbSe₂ and the formation of a vortex lattice on the CrBr₃ layer in experiments under an external magnetic field. The results contribute to the broader framework of exploiting proximity effects to realize novel phenomena in 2D heterostructures.

2D magnetic materials constitute an ideal platform to experimentally access the fundamental physics of magnetism in reduced dimensions.^[1–3] Furthermore, because of the ease of fabricating heterostructures, ferromagnetic van der Waals (vdW) materials present attractive opportunities for designer 2D magnetic,^[4,5] magnetoelectric,^[6] and magneto-optical artificial heteromaterials.^[7] As the different components in a vdW heterstructure only interact via weak vdW forces, the properties of the constituent materials are not strongly modified. This means

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that one can-for example-imprint magnetic properties of 2D magnets to the other layers without modifying their intrinsic properties and create novel spintronic and magnonic devices.^[8–10] This designer concept can be utilized in systems combining magnetism with superconductivity to realize topological superconductivity.[11,12] It is currently attracting intense attention due to its potential role in building blocks for Majorana-based qubits for topological quantum computation.^[12-14] While there are very few potential real materials exhibiting topological superconductivity,[15-18] in a designer material the desired physics emerges from the engineered interactions between the different components. For topological superconductivity, one needs to combine s-wave superconductivity with

magnetism and spin-orbit coupling to create an artificial topological superconductor.^[12,19] However, the coupling between the components is highly sensitive to the interfacial structure and electronic properties^[2,20] and thus, vdW materials with atomically sharp and highly uniform interfaces are an attractive platform with which to realize and harness exotic electronic phases arising in designer materials.

Layered materials that remain magnetic down to the monolayer (ML) limit have been recently demonstrated.^[4,5,21] While the first reports relied on mechanical exfoliation for the sample preparation, related materials chromium tribromide (CrBr₃) and Fe₃GeTe₂ have also been grown using molecular-beam epitaxy (MBE) in ultra-high vacuum (UHV),^[22,23] which is essential for realizing clean edges and interfaces. The inherent lack of surface bonding sites due to the layered nature of these materials prevents chemical bonding between the layers and results in a better control of the interfaces. Recently, we have successfully fabricated a superconducting ferromagnetic hybrid system based on vdW heterostructures using MBE.^[24,25] More importantly, by combining spin-orbit coupling, 2D ferromagnetic CrBr₃, and superconducting niobium diselenide (NbSe₂), we have demonstrated the existence of the 1D Majorana edge modes using low-temperature scanning tunneling microscopy (STM) and scanning tunneling spectroscopy (STS).^[25] However, for future applications, further systematic studies are desired for a better understanding of the electronic and magnetic properties of monolayer CrBr₃ grown on a NbSe₂ substrate.







Figure 1. Growth of CrBr₃ on NbSe₂. a) Computed top and side views of the CrBr₃/NbSe₂ heterostructure. b) Core-level spectra of CrBr₃/NbSe₂ heterostructure. The pass energy was 80 eV for the black curve and 20 eV for colored curves. c) STM image of a monolayer thick CrBr₃ grown on NbSe₂ using MBE (STM feedback parameters: $V_{\text{bias}} = +1$ V, I = 10 pA, scale bar: 39 nm). d) Atomically resolved image on the CrBr₃ layer. The moiré unit cell is denoted by the large rhombus (STM feedback parameters: $V_{\text{bias}} = +2$ V, I = 0.5 nA, scale bar: 3 nm). e) Calculated constant-current STM image of a monolayer of CrBr₃ on NbSe₂: $V_{\text{bias}} = +2.0$ V, scale bar: 3 nm. The inset in (e) shows a zoom in of the calculated STM image, with the atomic structure of the CrBr₃ superimposed.

In this work, we report a detailed characterization of monolayer CrBr₃ on NbSe₂ (CrBr₃/NbSe₂ hereafter) using low-temperature STM/STS and X-ray photo-electron spectroscopy (XPS). Combining magneto-optical Kerr effect (MOKE) measurements and density-functional theory (DFT) calculations, we unambiguously confirm the ferromagnetism of monolayer CrBr₃ on a NbSe₂ substrate. Our results give further experimental information on the magnetic properties of monolayer CrBr₃, and demonstrate a clean and controllable platform for creating superconducting-ferromagnetic heterostructure with a great potential for integration into future electronic devices that could be controlled externally through electrical,^[6] mechanical,^[26] chemical,^[27] or optical means.^[28]

In order to study the proximity effects through DFT calculations, we set up a $CrBr_3/NbSe_2$ bilayer heterostructure considering a 2 × 2 supercell for the NbSe₂ monolayer below a 1 × 1 cell of $CrBr_3$ monolayer as shown in **Figure 1**a, where the 1 × 1 $CrBr_3$ consists of Cr atoms arranged in a honeycomb lattice structure and each atom is surrounded by an octahedron of six Br atoms. The energetically most favorable stacking has one Cr atom located on top of a Se₂ pair, while the other Cr atom is on top of the hole site of the NbSe₂ (see Experimental Section for details of the calculation). The fully relaxed lattice parameters of the heterostructures reveal that the CrBr₃ has a tensile strain of about 7 %, while the NbSe₂ is compressed by less than 2 %, which are not sufficient to drastically affect their electronic and magnetic properties.^[29,30] XPS spectra for

the low binding energy region shown in Figure 1b indicate the presence and stoichiometry of CrBr₃ on the surface. The Cr 2p spectrum shown in Figure S7 of the Supporting Information confirms that there is only Cr(III) on the surface. Figure 1c shows a large scale STM image illustrating the typical morphology of the monolayer CrBr3 grown on NbSe2. The monolayer CrBr₃ islands are atomically flat and up to 200 nm in size, while clean areas of the bare NbSe2 substrate are clearly exposed. While the majority of monolayer islands are CrBr₃, we have consistently observed monolayer CrBr2 regions (less than 1% of the CrBr3 area) across several STM images and sample preparations as marked with a red arrow in Figure 1c (details given in Figure S4, Supporting Information). Figure 1d shows an atomically resolved STM image of the CrBr3 monolayer, revealing periodically spaced triangular protrusions. These features are formed by the three neighboring Br atoms as highlighted in the Figure 1e showing the simulated STM topographic image obtained through DFT calculations. Finally, the STM topography exhibits a clear, well-ordered superstructure with 6.3 nm periodicity. This superstructure is explained by the fact that when the CrBr₃ and NbSe₂ lattices are overlaid, 19 NbSe₂ unit cells accommodate 10 unit cells of CrBr₃, thus forming a 6.3 nm × 6.3 nm superstructure (a moiré pattern) as observed in the STM images of CrBr3 as shown in Figure 1d. It is important to note that the topographic contrast of the moiré pattern is bias-dependent (Figure S3, Supporting Information). The rotationally misaligned CrBr₃ domains have a slight effect







Figure 2. a) Typical long-range experimental d/dV_b spectra on a ML CrBr₃ on the NbSe₂ substrate. b) Simulated spin polarized projected density of states (PDOS) on the CrBr₃ layer of the CrBr₃/NbSe₂ heterostructure (continuous lines) and on pristine CrBr₃ layer (dashed lines). c) Band structure of the pristine CrBr₃ layer (dashed lines) and CrBr₃/NbSe₂ heterostructure (continuous lines). The E_F of the pristine CrBr₃ was set by aligning its conduction band minimum (CBM) with the correspondent CBM in the heterostructure.

on the moiré periodicity (Figure S1, Supporting Information). Additionally, the periodicity of the moiré pattern matches quite well with the lattice parameter of the CrBr₃ monolayer obtained through DFT (6.37 Å), suggesting that it is most likely unstrained in the CrBr₃/NbSe₂ heterostructure.

We experimentally determined the electronic structure of the CrBr₃/NbSe₂ heterostructure using STS measurements and compared the results directly with DFT calculations. **Figure 2**a shows a typical STM dI/dV_b spectrum of monolayer CrBr₃ acquired over a large bias range (a detailed comparison with bare NbSe₂ spectra is given in the Figure S5, Supporting Information). In the filled state regime (bias voltage $V_b < 0$), the spectrum is relatively flat and featureless until $V_b \approx -1$ V is reached, where the dI/dV_b slightly increases, and a steep rise is seen at $V_b \approx -1.5$ V. The dominant feature in the empty state regime ($V_b > 0$) of the dI/dV_b spectrum starts with a small bump around ≈ 0.5 V and a steep rise in dI/dV_b at ≈ 1.2 V, as

shown in Figure 2a. Those features, apart from a rigid shift of \approx 0.5 eV, are consistent with the DFT spin polarized projected density of states (PDOS) on the CrBr₃ layer of the heterostructure shown in Figure 2b. The steep rises in the $dI/dV_{\rm b}$ spectrum are around 3 V apart and mostly arise from the spin up bands of the CrBr₃ layer: its electronic properties are well preserved in the heterostructure as compared to the pristine CrBr₃ layer, as can be seen in Figure 2b,c. The band structures and PDOS shown in Figure 2c reveal that the bands in the [-2.0, -1.0] eV and [-1.0, 1.0] eV windows have a majority contribution from the NbSe₂ layer, where the NbSe₂ d-band in the [-1.0, 1.0] eV window is completely preserved and slightly spin polarized due to the proximity with the magnetic CrBr₃. However, the PDOS on the CrBr₃ layer in the [-2.0, -1.0] eV and [-1.0, 1.0] eV windows are nonzero and consistent with the bumps in the dI/dV_b spectrum of Figure 2a. The differential charge density of the CrBr3/NbSe2 heterostructure shown in Figure 3a reveals that



Figure 3. a) Differential charge density of the CrBr₃/NbSe₂ heterostructure, where the yellow and blue colors indicate charge accumulation (+) and depletion (-), respectively (isovalue = 3×10^{-4} a.u.). b) Magnetic hysteresis measured on the CrBr₃/NbSe₂ heterostructure in an out-of-plane magnetic field at several different temperatures (indicated in the figure).



charge accumulates at the interface between the layers, as well as around the Cr and Nb atoms, while charge depletes from the Br and Se atoms. Due to this charge reconfiguration close to the CrBr₃ layer, nonzero states from the Cr and Br atoms are observed within the band gap of the pristine CrBr₃ layer, which is consistent with the small bumps observed in the d*I*/ d*V*_b spectra shown in Figure 2a. Such charge reconfiguration is also observed on other similar CrBr₃/transition metal dichalcogenides (TMDs) and CrI₃/TMDs heterostructures.^[31]

After the electronic characterization of the samples, we will next focus on their magnetic properties. The isolated CrBr₃ layer has a predicted out-of-plane magnetic moment of 6.000 $\mu_{\rm B}$ per unit cell, where each Cr atom has three unpaired electrons. Our DFT calculations show that the magnetism of the CrBr₃ layer is well-preserved in the heterostructure, which shows a slightly larger magnetic moment of 6.097 $\mu_{\rm B}$ per unit cell due to induced magnetization on the NbSe2 layer. The PDOS on the CrBr₃ layer of the heterostructure reveals that the majority spin up channel has a band gap of 3 eV, while the minority spin down channel has a band gap of around 5 eV, both shown in blue and red, respectively, in Figure 2c. We study the truly 2D itinerant ferromagnetism in the CrBr₃ monolayer on NbSe₂ using magneto-optical Kerr effect (MOKE) microscopy. The magnetic field was applied perpendicular to the sample using a configuration sensitive to out-of-plane magnetization (further details of the experimental procedures are given the Experimental Section). Figure 3b shows the MOKE signal of a CrBr₃ monolayer on NbSe₂ as a function of the external magnetic field at several different temperatures. Notably, monolayer CrBr₃ is ferromagnetic, as evidenced by the prominent hysteresis seen here. As the temperature is increased, the hysteresis loop shrinks and eventually disappears at a transition temperature T_c of about 16 K. Similar behavior has been observed for a mechanically exfoliated monolayer CrBr₃ flake, where the transition temperature T_c was around 27 K.^[32] Moreover, the out-ofplane coercive field H_c for an exfoliated monolayer CrBr₃ flake at 5 K has been measured to be $\approx 8-20 \text{ mT}^{[28,32,33]}$ while in our MBE grown CrBr3 monolayer on a NbSe2 substrate the out-ofplane coercive field is around 2.5 mT at 7 K. The temperatures stated here are for the cold finger of the cryostat rather than the sample, which may partially explain the discrepancy with previous experiments. Furthermore, our CrBr₃ layer consists of disconnected, sub-micron islands, which are significantly smaller than typical exfoliated flakes, which may be expected to reduce T_c . This may also lead to the small coercivity of our layer, although for out-of-plane magnetized layers the measured coercivity is strongly dependent on extrinsic factors, which makes comparison with other systems difficult.

After confirming the existence of ferromagnetism in the $CrBr_3/NbSe_2$ heterostructure, it is interesting to see the effects of the superconducting NbSe₂ substrate on the CrBr₃ monolayer. Isolated CrBr₃ is a ferromagnetic insulator; however, due to the monolayer thickness, it is possible to tunnel through such a structure with STM. In addition, due to the charge transfer at the interface between CrBr₃ and NbSe₂, the heterostructure itself has a metallic nature. Therefore, one can expect a measurable interaction between CrBr₃ and NbSe₂. The superconductivity of the CrBr₃/NbSe₂ heterostructure was studied by STM at T = 350 mK. Figures 4a,b show experimental dI/dV_b spectra (raw data) taken on a bare NbSe₂ substrate and on monolayer CrBr₃, respectively. The dI/dV_b spectrum of bare NbSe₂ (Figure 4a) has a hard gap with an extended region of zero differential conductance around the Fermi energy. dI/dV_b spectra were fitted by the McMillan two-band model^[34] (parameters given in the Supporting Info). In contrast, the spectra taken in the middle of the CrBr₃ island have small but distinctly nonzero differential conductance inside the gap of the NbSe₂ substrate. We observe pairs of conductance onsets at ±0.3 mV around zero bias. This feature results from the formation of Shiba-bands in the NbSe₂ caused by the induced magnetization from the monolayer CrBr₃.^[25,35] These extra features are not reproduced by the two-band model (Figure 4b, fit parameters given in the Supporting Information).

To obtain more detailed insight into the superconductivity of the CrBr₃/NbSe₂ heterostructure, we investigate the dependence of our dI/dV_b spectra under an applied out-of-plane magnetic field. In a type-II SC such as NbSe2, we would expect to observe an Abrikosov vortex lattice in a dI/dV_b map acquired near the energy of the superconducting gap.[36] Figure 4d-f shows dI/dV_b grid maps at 0, 0.6, and 0.8 mV bias voltages, respectively. The maps are recorded under 0.65 T out-of-plane magnetic field on an area with both CrBr3 islands and the bare NbSe₂ surface (Figure 4c). It is seen from Figure 4d-f that the vortices exhibit a highly ordered hexagonal lattice similar to those observed on the clean NbSe2 surface. This is the first time vortices have been clearly observed in a hybrid ferromagnetsuperconductor-system. We measured the spatial variation of the $dI/dV_{\rm b}$ spectra as a function of distance away from the vortex center (along the dashed line in Figure 4d). The results are given in Figure 4g, which shows the measured dI/dV_b as functions of distance and sample bias V on a color scale (spatially resolved dI/dV_h line spectra of a vortex core state in bare NbSe₂ are given in Figure S6, Supporting Information). One can see that only one peak appears at zero-bias in the $dI/dV_{\rm b}$ spectra near the vortex center, and this peak splits into two away from the vortex core. The splitting energy increases linearly with distance. One of the intriguing properties of a topological superconductor is that vortices on its surface are expected to host Majorana zero modes.[37] This mode results in a peak in the local density-of-states at the Fermi energy in the center of the vortex. In contrast to bound states in vortices on conventional superconductors, a Majorana mode should not split in energy away from the vortex center.^[37–39] Due to the broadening of the resonance in the vortex spectra, we cannot resolve the individual components in the dI/dV_b spectra and the zero bias feature persists up to 5 nm from the vortex core before the clearly split features can be observed. This is within the range of spatial distributions of the Majorana zero mode reported in the literature (a few nm up to 30 nm).^[38-41] In addition, it is important to note that Majorana zero modes in vortex cores have only been observed at low magnetic field (e.g., 0.1 T for Bi₂Te₃/ NbSe₂^[38,41]) and its amplitude is expected to decay exponentially as the external field is increased. In order to confirm whether the vortices in our system host Majorana zero modes at their cores, further experiments, in particular using spin-polarized tunneling measurements,^[42] are clearly necessary. In summary, we have provided experimental evidence for the realization of a 2D ferromagnet-superconductor van der Waals heterostructure.







Figure 4. a,b) Experimental dI/dV_b spectroscopy (black) on the NbSe₂ substrate (a) and in the middle of a CrBr₃ island (b) measured at T = 350 mK. We also show a fit to a double gap s-wave BCS-type model (red). c) STM topography image (STM feedback parameters: $V_{\text{bias}} = +1$ V, I = 10 pA, scale bar: 22 nm). d–f) Vortex imaging on CrBr₃/NbSe₂ heterostructure. We have recorded grid spectroscopy (100 × 100 spectra) over an area of 110 × 110 nm² at T = 350 mK under an applied out-of-plane magnetic field of 0.65 T. The maps are obtained from full spectroscopic scans from –3 to 3 mV at each pixel at the indicated bias voltages. g) Line scan of the dI/dV_b signal along the white line marked in (d).

More importantly, we have experimentally confirmed that the CrBr₃ monolayer retains its ferromagnetic ordering with a magnetocrystalline anisotropy favoring an out-of-plane spin orientation on NbSe₂. Our DFT calculations showing an induced moment in Nb from hybridization with Cr d-orbitals confirm the imprinting of magnetic order on NbSe₂ from a 2D vdW magnetic insulator. Our results provide a broader framework for employing other proximity effects to tailor materials and realize novel phenomena in 2D heterostructures.

Experimental Section

MBE Sample Growth: The CrBr₃ thin film was grown on a freshly cleaved NbSe₂ substrate by compound source MBE. The anhydrous CrBr₃ powder of 99 % purity was evaporated from a Knudsen cell. Before growth, the cell was degassed up to the growth temperature 350°C until the vacuum was better than 1×10^{-8} mbar. The sample was heated by electron beam bombardment and temperatures were measured using an optical pyrometer. The growth speed was determined by checking the coverage of the as-grown samples by STM. The optimal substrate temperature for the growth of CrBr₃ monolayer films was ~270°C. Below this temperature, CrBr₃ forms disordered clusters on the NbSe₂ surface. The NbSe₂ crystal is directly mounted on a sample holder using a two component conducting silver epoxy which only allows us to heat the sample up to ~300°C.

STM and STS Measurements: After the sample preparation, it was inserted into a low-temperature STM (Unisoku USM-1300) housed in the same UHV system and all subsequent experiments were performed at T = 350 mK. STM images were taken in constant-current mode. dI/ dV_b spectra were recorded by standard lock-in detection while sweeping

the sample bias in an open feedback loop configuration, with a peak-topeak bias modulation of 30–50 μ V for a small bias range and 10 mV for a lager bias range, respectively at a frequency of 707 Hz. Spectra from grid spectroscopy experiments were normalized by the normal state conductance, that is, dI/dV_b at a bias voltage corresponding to a few times the superconducting gap.

Sample Transfer: After sample measurement in STM, the sample was transferred to the load lock ($\approx 10^{-9}$ mbar). We connected a glove bag directly to the load lock and vented it slowly with pure nitrogen. The sample was then transferred via the glove bag for XPS and MOKE measurements.

XPS Experiments: The XPS spectra were measured using a Kratos Axis Ultra system, equipped with monochromatic Al K_{α} X-ray source. All measurements were performed using an analysis area of 0.3 mm \times 0.7 mm. The black curve in Figure 1b was measured using 80 eV pass energy and 1 eV energy step whereas the colored curves were taken with 20 eV pass energy and 0.1 eV energy step. The energy calibration was done using the C 1s peak at 284.8 eV.

MOKE Measurements: MOKE was carried out using an Evico Magnetics system based on a Zeiss Axio Imager D1 microscope with a Hamamatsu C4742-95 digital camera. The sample was placed in a Janis research ST-500 cold finger cryostat with optical access and cooled using liquid He. Imaging of the sample was carried out in a polar Kerr configuration under an out-of-plane magnetic field. Hysteresis loops were constructed from images taken using a long working distance 100× lens after background image subtraction and corrected for a linear background slope due to the Faraday effect on the lens.

DFT Calculations: Calculations were performed with the DFT methodology as implemented in the periodic plane-wave basis VASP code.^[43,44] Atomic positions and lattice parameters were obtained by fully relaxing all structures using the spin-polarized Perdew–Burke–Ernzehof functional^[45] including Grimme's semiempirical DFT-D3 scheme for dispersion correction,^[46] which is important to describe the vdW interactions between the CrBr₃ and the NbSe₂ layers. The stacking



of the layers used in the calculations is the same used in a previous work.^[25] The convergence criterion of self-consistent field computation was set to 10⁻⁵ eV and the threshold for the largest force acting on the atoms was set to less than 0.012 eV Å⁻¹. A vacuum layer of 12 Å was added to avoid mirror interactions between periodic images. Further calculations of band structures and density of states were realized using the hybrid Heyd–Scuseria–Ernzerhof (HSE06) functional,^[47–49] which improves the description of the band structure as compared to the PBE functional. The interactions between electrons and ions were described by PAW pseudopotentials, where 4s and 4p shells were added explicitly as semicore states for Nb and 3p shells for Cr. An energy cutoff of 550 eV was used to expand the wave functions and a systematic *k*-point convergence was checked, where the total energy was converged to the order of 10⁻⁴ eV. Spin polarization was considered by setting an initial out-of-plane magnetization of 3 μ_B per Cr atom and zero otherwise.

Supporting Information

Supporting Information is available from the Wiley Online Library or from the author.

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Conflict of Interest

The authors declare no conflict of interest.

Keywords

chromium tribromide | magnetic 2D materials, niobium diselenide, superconductors, van der Waals heterostructures

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